GT0104
4-Bit Bidirectional Voltage-Level Translator

1 Features

- No direction-control
- Data rates
24 Mbps (Push Pull)
2 Mbps (Open Drain)
- 1.65 V to 3.6 V on A port and 2.3 V to 5.5 V on B port ($V_{CCA} \leq V_{CCB}$)
- VCC isolation feature: If either VCC input is at GND, both ports are in the high-impedance state
- No power-supply sequencing required:
either V_{CCA} or V_{CCB} can be ramped first
- I_{off} supports partial-power-down mode operation
- Operating temperature range:-40℃ to +85℃

2 Application

- Handset/Smartphone
- MART
- IPC
- GPIO

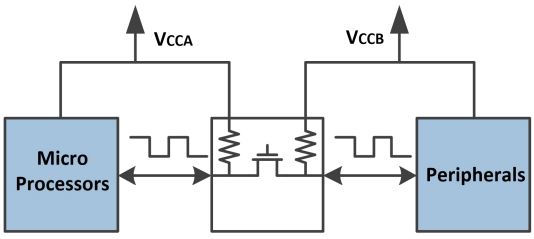
3 Description

This 4-bit non-inverting translator is a bidirectional voltage-level translator and can be used to build digital switching compatibility between multi voltage systems. It uses two separate configurable power supply rails that including A ports supporting operating voltages from 1.65 V to 3.6 V with tracking V_{CCA} supply, and also including B ports supporting operating voltages from 2.3 V to 5.5 V with tracking V_{CCB} supply.

The advantage above provides the support of both lower and higher logic signal levels while providing bidirectional translation capabilities between any of the 1.8-V, 2.5-V, 3.3-V, and 5- V voltage circuit points.

Placing output-enable (OE) input to low level, all I/Os are forced to high-impedance state that significantly lower the quiescent current consumption. In order to ensure the high-impedance state during power up or power down, OE pin should be tied to GND via a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Circuit Diagram



4 Revision History

Revision	Date	Note
Rev.A1.0	2023. 09. 21	Original Version
Rev.A1.1	2023. 09. 09	Additional Switch Characteristics Data
Rev.A1.2	2023. 10. 24	1.Update Package Qty 2.Added Tape and Reel Information
Rev.A1.3	2023. 12. 18	Update New Package
Rev.A1.4	2024. 01. 26	Updated Part Name

The latest datasheet version should be checked on the GTIC official website, as the company does not actively inform customers about updates to the datasheet.

5 Device Summary, Pin and Packages

Table 5-1. Device Summary(1)

Serial Name	Part Name	Package	Body Size (Nom)	Marking(2)	MSL(3)	Package Qty
GT0104	GT0104QD	QFN3.5×3.5-14L	3.50mm×3.50mm	GT0104 XXXXX	3	Tape and Reel,5000
	GT0104SC	QFN2.0×2.0-12L	2.00mm×2.00mm	0104 XXXX	3	Tape and Reel,3000
	GT0104TD	TSSOP-14	5.00mm×4.40mm	GT0104 XXXXXXX	3	Tape and Reel,4000
	GT0104QC	QFN2.0×1.7-12L	2.00mm×1.70mm	0104 XXXX	3	Tape and Reel,4000

(1)For all available packages, please contact product sales.
(2)There may be additional marking, which relates to the lot trace code information (data code and Vendor code), the logo or the environmental category on the device.
(3)MSL, The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.
(4)"XXXXX" in Marking will be appeared as the batch code.
FAE: 13148878879

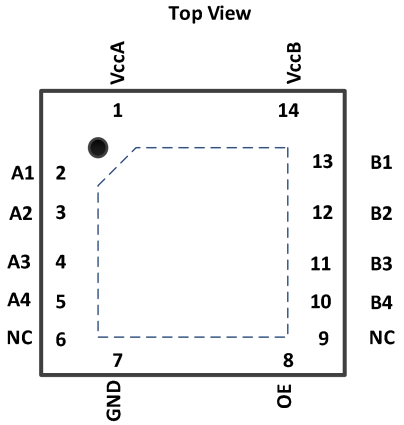


Fig.5-1. GT0104: QD (QFN3.5×3.5-14L) Package

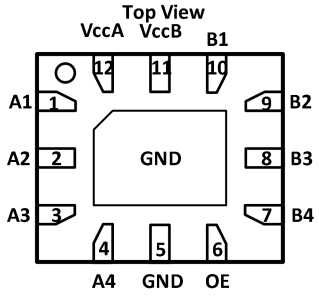


Fig.5-2. GT0104: SC (QFN2.0×2.0-12L) Package

5 Device Summary, Pin and Packages (Continued)

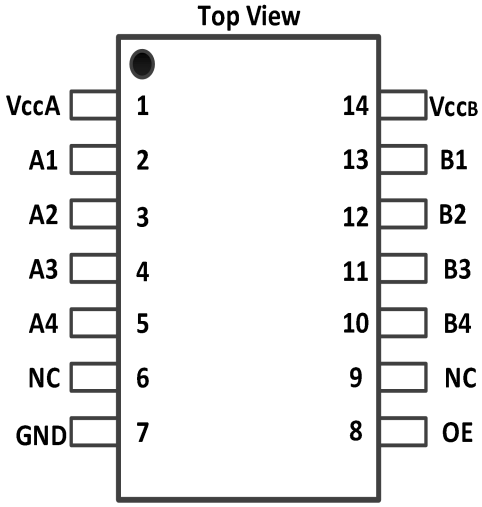


Fig.5-3. GT0104: TD (TSSOP14) Package

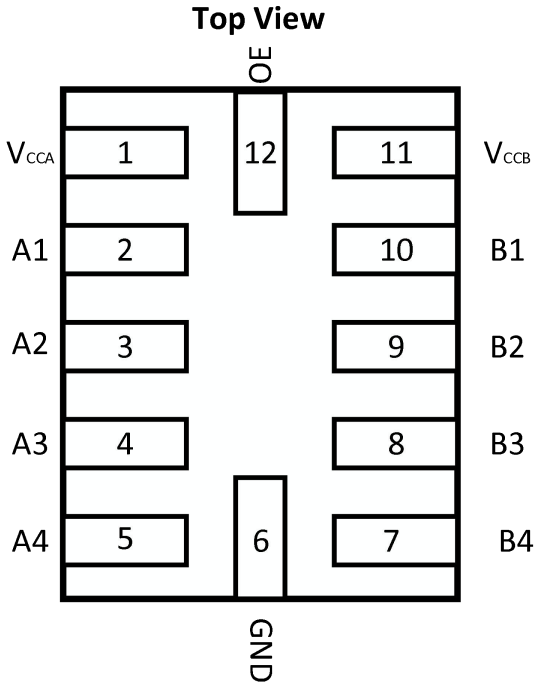


Fig.5-4. GT0104: QC (12-Pin QFN) Package

5 Device Summary, Pin and Packages (Continued)

Table 5-1 Pin Definition

Pin					I/O	Function
Name	QD	SC	TD	QC		
V_{CCA}	1	12	1	1	-	A Port Supply Voltage. 1.65V≤VccA≤3.6V and VccA≤VccB
A1	2	1	2	2	I/O	Input/Output A1. Referenced to $V_{CCA.}$
A2	3	2	3	3	I/O	Input/Output A2. Referenced to $V_{CCA.}$
A3	4	3	4	4	I/O	Input/Output A3. Referenced to $V_{CCA.}$
A4	5	4	5	5	I/O	Input/Output A4. Referenced to $V_{CCA.}$
NC	6	-	6	-	-	No internal connection
GND	7	5	7	6	-	Ground
OE	8	6	8	12	I	Output Enable(Active High).Pull OE low to place all outputs in 3-state mode. Referenced to $V_{CCA.}$
NC	9	-	9	-	-	No internal connection
B4	10	7	10	7	I/O	Input/Output B4. Referenced to $V_{CCB.}$
B3	11	8	11	8	I/O	Input/Output B3. Referenced to $V_{CCB.}$
B2	12	9	12	9	I/O	Input/Output B2. Referenced to $V_{CCB.}$
B1	13	10	13	10	I/O	Input/Output B1. Referenced to $V_{CCB.}$
V_{CCB}	14	11	14	11	-	B Port Supply Voltage. 2.3V≤VccB≤5.5V

*It is suggested to leave the unconnected pins floating.

6 Voltage, Temperature, ESD and Thermal Ratings

6.1 Absolute Maximum Ratings

Parameters		Min	Max	Unit
Supply voltage, V_{CCA}		-0.3	6.0	V
Supply voltage, V_{CCB}		-0.3	6.0	V
Input voltage range,V_I	A port	-0.3	6.0	V
	B port	-0.3	6.0	
Voltage range applied to any output in the high-impedance or power-off state, Vo	A port	-0.3	6.0	V
	B port	-0.3	6.0	
Voltage range applied to any output in the high or low state, Vo	A port	-0.3	V_{CCA}+0.3	V
	B port	-0.3	V_{CCA}+0.3	
Input clamp current,I_{IK}	V_I＜0		-50	mA
Output clamp current,I_{OK}	V_O＜0		-50	mA
Continuous output current,I_O			±50	mA
Continuous current through V_{CCA},V_{CCB} or GND			±100	mA
Maximum junction temperature			150	℃
Storage temperature range		-65	150	℃

(1)Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2)The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed

(3)The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

6 Voltage, Temperature, ESD and Thermal Ratings(continued)

6.2 ESD Ratings

ESD			Value	Unit
V(ESD)	Electrostatic discharge	Human-Body Model (HBM)	±3K	V
		Machine Model (CDM)	±2K	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

V_{CCI} is the supply voltage associated with the input port.V_{CCO} is the supply Voltage associated with the output port.

Parameter	Conditions		Min	Typ	Max	Unit
Supply voltage (1)	V_{CCA}		1.65		3.6	V
	V_{CCB}		2.3		5.5	
High-level input voltage(V_{IH})	A-port I/Os	V_{CCA}=1.65 V to 1.95 V V_{CCB}=2.3 V to 5.5 V	V_{CCI}-0.2		V_{CCI}	V
		V_{CCA}=2.3 V to 3.6 V V_{CCB}=2.3 V to 5.5 V	V_{CCI}-0.4		V_{CCI}	
	B-port I/Os	V_{CCA}=1.65 V to 3.6V V_{CCB}=2.3 V to 5.5 V	V_{CCI}-0.4		V_{CCI}	
	OE input	V_{CCA}=1.65 V to 3.6 V V_{CCB}=2.3 V to 5.5 V	$V_{CCI}\times 0.8$		5.5	
Low-level input voltage(VIL)(2)	A-port I/Os	V_{CCA}=1.65 V to 1.95 V V_{CCB}=2.3 V to 5.5 V	0		0.15	V
	B-port I/Os	V_{CCA}=1.65 V to 3.6 V V_{CCB}=2.3 V to 5.5 V	0		0.15	
OE	OE input	V_{CCA}=1.65 V to 3.6 V V_{CCB}=2.3 V to 5.5 V	0		$V_{CCA}\times 0.25$	V
Input transition rise or fall rate(Δt/Δv)	A-port I/Os push-pull driving				10	ns/V
	B-port I/Os push-pull driving				10	
	Control input				10	
TA Operating free-air temperature	-		-40		85	℃

(1) V_{CCA} must be less than or equal to V_{CCB}.

(2) The maximum V_{IL} value is provided to ensure that a valid V_{OL} is maintained. The V_{OL} value is V_{IL} plus the voltage drop across the pass gate transistor.

7 Electrical Specifications

7.1 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (1) (2) (3)

Parameter		Conditions	V_{CCA}	V_{CCB}	Temp	Min	Typ	Max	Unit
V_{OHA}	Port A Output High Voltage	I_{OH}=–20 μA $V_{IB} \geq V_{CCB} - 0.4V$	1.65V to 3.6V	2.3V to 5.5V	Full	V_{CCA}×0.7			V
V_{OLA}	Port A Output Low Voltage	I_{OL}=1mA $V_{IB} \leq 0.15$ V	1.65V to 3.6V	2.3V to 5.5V	Full			0.3	V
V_{OHB}	Port B Output High Voltage	I_{OH}=–20 μA $V_{IA} \geq V_{CCA} - 0.4V$	1.65V to 3.6V	2.3V to 5.5V	Full	V_{CCA}×0.7			V
V_{OLB}	Port B Output Low Voltage	I_{OL}=1mA $V_{IA} \leq 0.15$ V	1.65V to 3.6V	2.3V to 5.5V	Full			0.3	V
I_I	Input Leakage Current	OE	1.65V to 3.6V	2.3V to 5.5V	+25℃			±1	μA
					Full			±1.5	
I_{off}	Partial Power Down Current	A Ports	0V	0V to 5.5V	+25℃			±0.5	μA
					Full			±1	
		B Ports	0V to 3.6V	0V	+25℃			±0.5	
					Full			±1	
I_{OZ}	High-impedance State Output Current	A or B port OE=0V	1.65V to 3.6V	2.3V to 5.5V	+25℃			±0.5	μA
					Full			±1	
I_{CCA}	V_{CCA} Supply Current	V_I=V_O=open I_O=0	1.65V to V_{CCB}	2.3v to 5.5V	Full			2.5	μA
			3.6v	0V	Full			2.5	
			0v	5.5V	Full			-1	
I_{CCB}	V_{CCB} Supply Current	V_I=V_O=open I_O=0	1.65V to V_{CCB}	2.3v to 5.5V	Full			10	μA
			3.6v	0V	Full			-1	
			0v	5.5V	Full			1	
I_{CCA} + I_{CCB}	Combined Supply Current	V_I=V_{CCI} or GND I_O=0	1.65V to V_{CCB}	2.3v to 5.5V	Full			13	μA
I_{CCZA}	V_{CCA} Supply Current	V_I=V_{CCI} or 0V I_O=0, OE=0V	1.65V to V_{CCB}	2.3v to 5.5V	Full			1	μA
I_{CCZB}	V_{CCB} Supply Current	V_I=V_{CCI} or 0V I_O=0, OE=0V	2.3v to 3.6V	2.3v to 5.5V	Full			1	μA
C_i	Input Capacitance	OE	3.3V	3.3V	+25℃		2.5		PF
C_{io}	Input-to-output Internal Capacitance	A Port	3.3V	3.3V	+25℃		5		PF
		B Port	3.3V	3.3V	+25℃		5		

(1) V_{CCI} is the VCC associated with the input port.

(2) V_{CCO} is the VCC associated with the output port

(3) V_{CCA} must be less than or equal to V_{CCB}.

7 Electrical Specifications (Continued)

7.2 Timing Requirements

V_{CCA}=1.8V±0.15V

		V_{CCB}=2.5V±0.2V	V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Unit
		Typ	Typ	Typ	
Data Rate	Push-pull Driving	21	22	24	Mbps
	Open-drain Driving	2	2	2	
Pulse Duration(tw)	Push-pull Driving (Data Inputs)	47	45	41	ns
	Open-drain Driving (Data Inputs)	500	500	500	

V_{CCA}=2.5V±0.15V

		V_{CCB}=2.5V±0.2V	V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Unit
		Typ	Typ	Typ	
Data Rate	Push-pull Driving	20	22	24	Mbps
	Open-drain Driving	2	2	2	
Pulse Duration(tw)	Push-pull Driving (Data Inputs)	50	45	41	ns
	Open-drain Driving (Data Inputs)	500	500	500	

V_{CCA}=3.3V±0.15V

		V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Unit
		Typ	Typ	
Data Rate	Push-pull Driving	23	24	Mbps
	Open-drain Driving	2	2	
Pulse Duration(tw)	Push-pull Driving (Data Inputs)	43	41	ns
	Open-drain Driving (Data Inputs)	500	500	

7 Electrical Specifications (Continued)

7.3 Switching Characteristics: V_{CCA}=1.8V±0.15V

over recommended operating free-air temperature range (unless otherwise noted)

Parameter		Conditions		V_{CCB}=2.5V±0.2V	V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Units
				Typ	Typ	Typ	
t_{PHL}	Propagation Delay Time High-to-low Output	A to B	Push-pull Driving	5.6	5	5	ns
			Open-drain Driving	7.5	7.9	8.3	
t_{PLH}	Propagation Delay Time low-to-high Output	A to B	Push-pull Driving	10.0	9.5	9	ns
			Open-drain Driving	181	170	154	
t_{PHL}	Propagation Delay Time High-to-low Output	B to A	Push-pull Driving	7	7.1	7.2	ns
			Open-drain Driving	7.6	8.1	9.2	
t_{PLH}	Propagation Delay Time low-to-high Output	B to A	Push-pull Driving	7.6	6.9	6	ns
			Open-drain Driving	163	145	118	
t_{en}	Enable Time	OE to A or B		135	159	182	ns
t_{dis}	Disable Time	OE to A or B		170	174	181	ns
t_{rA}	Input Rise Time	A port rise time	Push-pull Driving	13.4	11.9	10.6	ns
			Open-drain Driving	68	66	62	
t_{rB}	Input Rise Time	B port rise time	Push-pull Driving	13	12	11.6	ns
			Open-drain Driving	66	65	50	
t_{fA}	Input Fall Time	A port fall time	Push-pull Driving	5.6	4.7	4.0	ns
			Open-drain Driving	5.0	5.1	5.2	
t_{fB}	Input Fall Time	B port fall time	Push-pull Driving	3.0	3.0	2.9	ns
			Open-drain Driving	6.1	5.6	4.4	
$t_{SK(O)}$	Skew(time), Output	Channel-to-Channel Skew		0.5	0.5	0.5	ns
Maximum Data Rate		Push-pull Driving		22	23	24	Mbps
		Open-drain Driving		2	2	2	

7 Electrical Specifications (Continued)

7.4 Switching Characteristics, V_{CCA}=2.5V±0.15V

over operating free-air temperature range (unless otherwise noted)

Parameter		Conditions		V_{CCB}=2.5V±0.2V	V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Units
				Typ	Typ	Typ	
t_{PHL}	Propagation Delay Time High-to-low Output	A to B	Push-pull Driving	3.5	3.5	3.2	ns
			Open-drain Driving	6.3	6.5	6.7	
t_{PLH}	Propagation Delay Time low-to-high Output	A to B	Push-pull Driving	4.5	4.9	4.7	ns
			Open-drain Driving	158	152	142	
t_{PHL}	Propagation Delay Time High-to-low Output	B to A	Push-pull Driving	3.7	3.9	4.6	ns
			Open-drain Driving	6	6.6	7.7	
t_{PLH}	Propagation Delay Time low-to-high Output	B to A	Push-pull Driving	4.8	4	2.5	ns
			Open-drain Driving	153	138	116	
t_{en}	Enable Time	OE to A or B		7.7	41.8	130	ns
t_{dis}	Disable Time	OE to A or B		175	181	182	ns
t_{rA}	Input Rise Time	A port Rise Time	Push-pull Driving	9.8	8.6	7.5	ns
			Open-drain Driving	79	77	65	
t_{rB}	Input Rise Time	B port Rise Time	Push-pull Driving	9.8	8.7	8.1	ns
			Open-drain Driving	93	68	53	
t_{fA}	Input Fall Time	A port Fall Time	Push-pull Driving	4.6	4.1	3.6	ns
			Open-drain Driving	5.1	5.1	5.2	
t_{fB}	Input Fall Time	B port Fall Time	Push-pull Driving	4.5	4.0	4.0	ns
			Open-drain Driving	6.9	7.4	7.8	
$t_{SK(O)}$	Skew(time), Output	Channel-to-Channel Skew		0.5	0.5	0.5	ns
Maximum Data Rate		Push-pull Driving		22	24	24	Mbps
		Open-drain Driving		2	2	2	

7 Electrical Specifications (Continued)

7.5 Switching Characteristics, V_{CCA} =3.3V±0.3V

over recommended operating free-air temperature range (unless otherwise noted)

Parameter		Conditions		V_{CCB}=3.3V±0.2V	V_{CCB}=5V±0.2V	Units
				TYP	TYP	
t_{PHL}	Propagation Delay Time High-to-low Output	A to B	Push-pull Driving	2.1	2.2	ns
			Open-drain Driving	5.9	6.1	
t_{PLH}	Propagation Delay Time High-to-low Output	A to B	Push-pull Driving	1	3.3	ns
			Open-drain Driving	138	131	
t_{PHL}	Propagation Delay Time High-to-low Output	B to A	Push-pull Driving	2.3	2.6	ns
			Open-drain Driving	5.4	6.6	
t_{PLH}	Propagation delay time low-to-high Output	B to A	Push-pull Driving	1.0	1.0	ns
			Open-drain Driving	133	115	
t_{en}	Enable Time	OE to A or B		4.7	5.2	ns
t_{dis}	Disable Time	OE to A or B		174	182	ns
t_{rA}	Input Rise Time	A port Rise Time	Push-pull Driving	7.4	6.6	ns
			Open-drain Driving	75	67	
t_{rB}	Input Rise Time	B port Rise Time	Push-pull Driving	7.7	7.1	ns
			Open-drain Driving	70	65	
t_{fA}	Input Fall Time	A port Fall Time	Push-pull Driving	3.4	3.0	ns
			Open-drain Driving	5.1	5.1	
t_{fB}	Input Fall Time	B port Fall Time	Push-pull Driving	3.5	3.2	ns
			Open-drain Driving	6.8	6.7	
$t_{SK(O)}$	Skew(time), Output	Channel-to-Channel Skew		0.5	0.5	ns
Maximum Data Rate		Push-pull Driving		24	24	Mbps
		Open-drain Driving		2	2	

8 Typical Characteristics

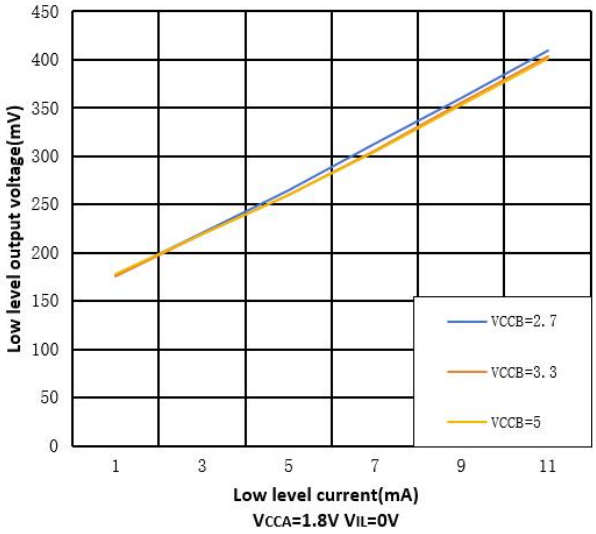


Fig.8-1. Low Level Output Voltage vs Low Level Current

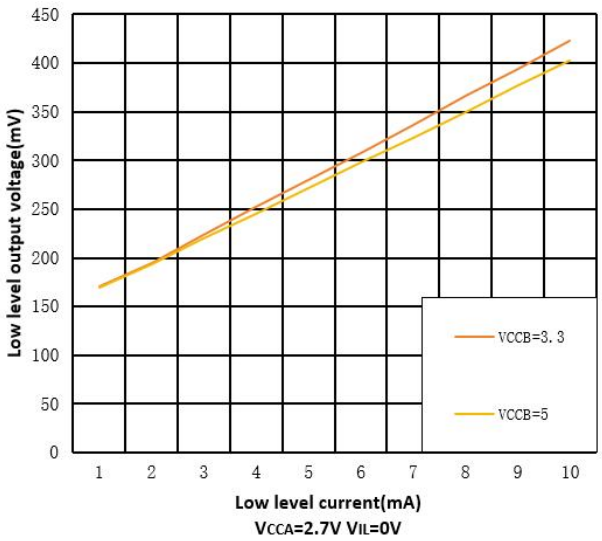


Fig.8-2. Low Level Output Voltage vs Low Level Current

9 Parameter Measurement Information

Unless otherwise noted, all input pulsed are supplied by generators having the following characteristics:

- PSRR 10MHz
- Zo=50 Ω
- dv/dt ≧1V/ns

Note: All input pulses are measured one at a time with one transition per measurement

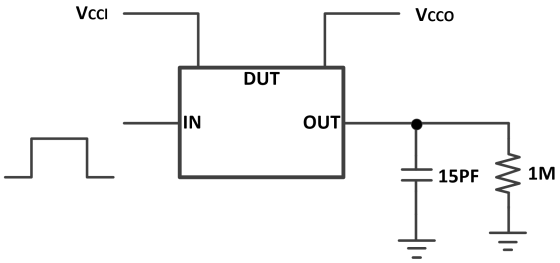


Fig.9-1. Data Rate, Pulse Duration, Propagation Delay, Output Rise and Fall Time Measurement Using a Push-Pull Driver

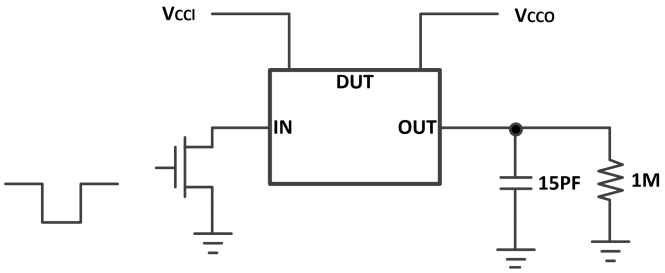


Fig.9-2. Data Rate, Pulse Duration, Propagation Delay, Output Rise and Fall Time Measurement Using an Open-Drain Driver

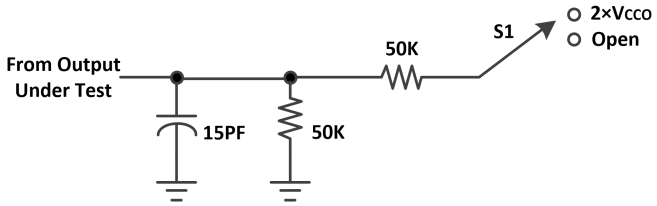


Fig.9-3. Load Circuit for Enable/Disable Time Measurement

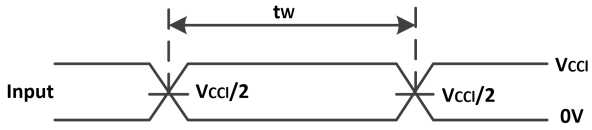
Table 9-1 Switch Configuration for Enable/Disable Timing

Test	S1
t_{PZL}(1), t_{PLZ}(2)	2×V_{CCO}
t_{PHZL}(1), t_{PZH}(2)	Open

(1) t_{PZL} and t_{PZH} are the same as ten.

(2) t_{PLZ} and t_{PHZ} are the same as tdis.

9 Parameter Measurement Information (Continued)



(1) All input pulses are measured one at a time, with one transition per measurement.

Fig.9-4. Voltage Waveforms Pulse Duration

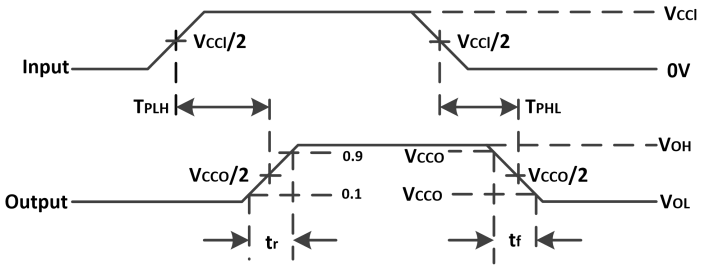


Fig.9-5. Voltage Waveforms Propagation Delay Times

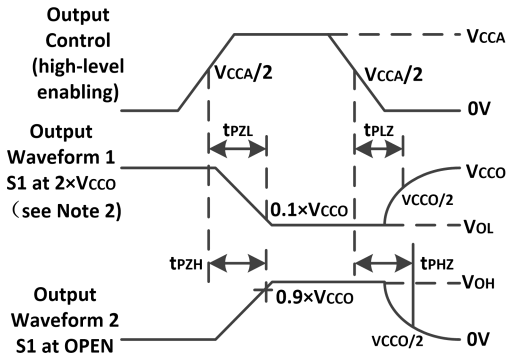


Fig.9-6. Voltage Waveforms Enable and Disable

10 Detailed Description

10.1 Overview

The GT0104 IC is a Bi-direction voltage-level translator specifically designed for translating logic voltage levels. The A port can accept I/O voltages that cover from 1.65 V to 3.6 V range; The B port can accept I/O voltages from 2.3 V to 5.5 V. The device is a pass-gate architecture with edge-rate accelerators (one-shots) to improve the overall data rate. 10-kΩ pullup resistors that usually used in open-drain applications have been integrated inside IC with the advantage saving an external resistor. Not only the IC is designed for open-drain applications, but also this device can translate push-pull CMOS logic outputs.

10.2 Architecture

The GT0104 architecture (see Figure below) is a translator with Bi-direction-Sensing function that means a direction-control mechanism to control the direction of data flow from A to B or from B to A is not needed. These two bidirectional channels independently determine the direction of data flow without a direction-control signal. This auto-direction feature is realized by each I/O pin can be automatically reconfigured as either an input or an output.

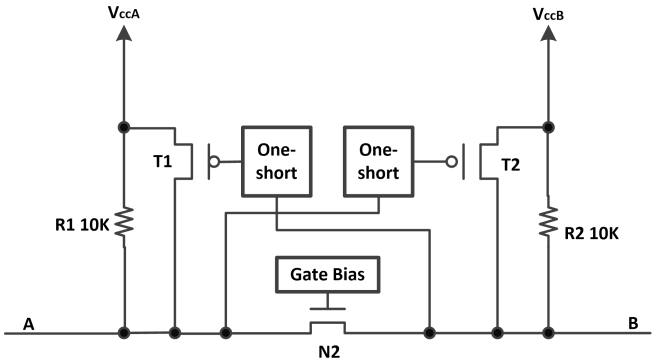


Fig.10-1. Architecture of GT0104

11 Application Information

The GT0104 device can be used to bridge the digital-switching compatibility gap between two voltage nodes to successfully interface logic threshold levels found in electronic systems. It should be used in a point-to-point topology for interfacing devices or systems operating at different interface voltages with one another. Its primary target application use is for interfacing with open-drain drivers on the data I/Os such as I2C or 1-wire, where the data is bidirectional and no control signal is available. The device can also be used in applications where a push-pull driver is connected to the data I/Os, but the GT0108 might be a better option for such push-pull applications.

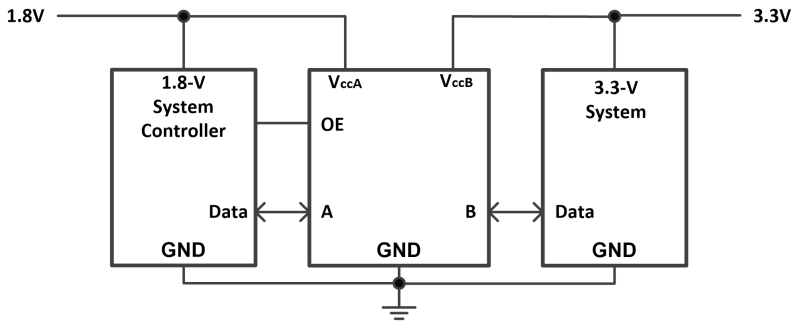
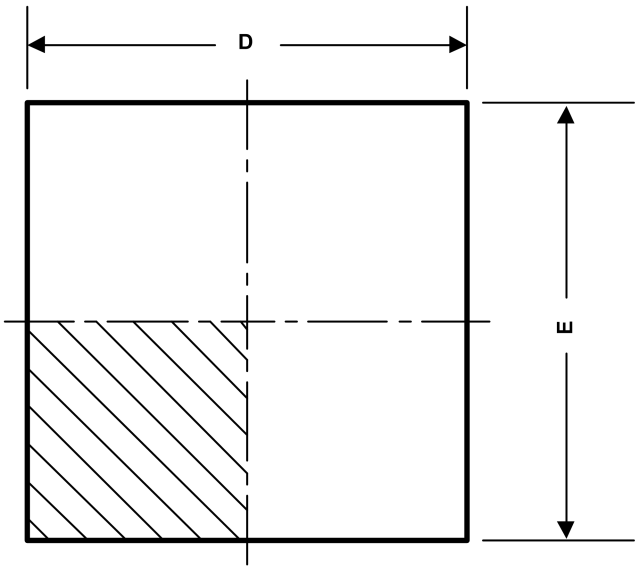


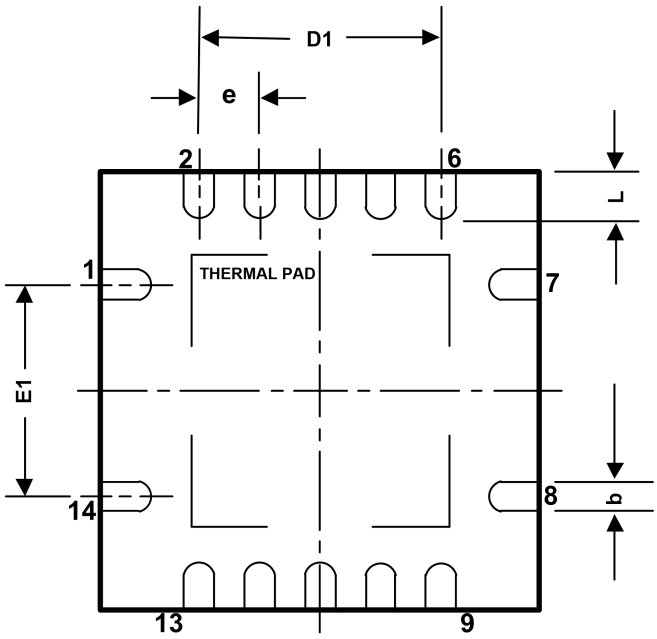
Fig.11-1. Typical Application Schematic

12 Package Outline Dimension

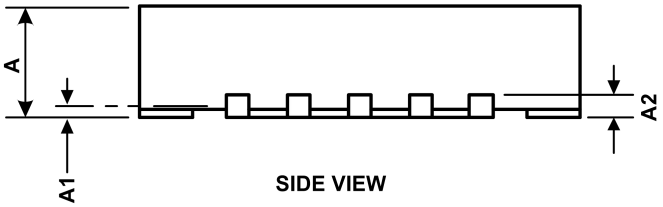
QFN3.5×3.5-14L



TOP VIEW



BOTTOM VIEW

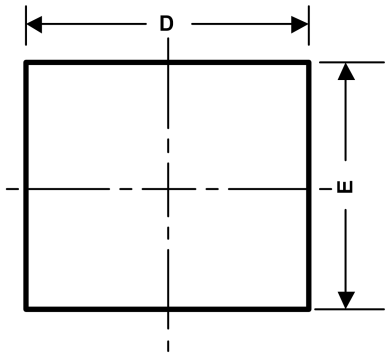


SIDE VIEW

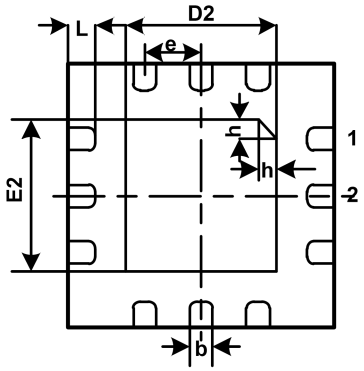
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.000	0.031	0.039
A1	0.000	0.050	0.00	0.002
A2	0.200REF		0.008REF	
b	0.180	0.300	0.007	0.012
D	3.350	3.650	0.132	0.144
D1	2.000TYP		0.079TYP	
E	3.350	3.650	0.007	0.012
E1	1.500TYP		0.059TYP	
e	0.500TYP		0.020TYP	
L	0.300	0.500	0.012	0.020

12 Package Outline Dimension(Continued)

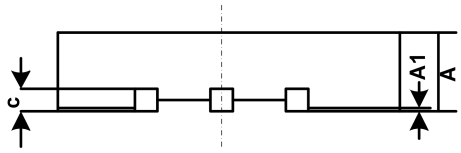
QFN2.0×2.0-12L



TOP VIEW



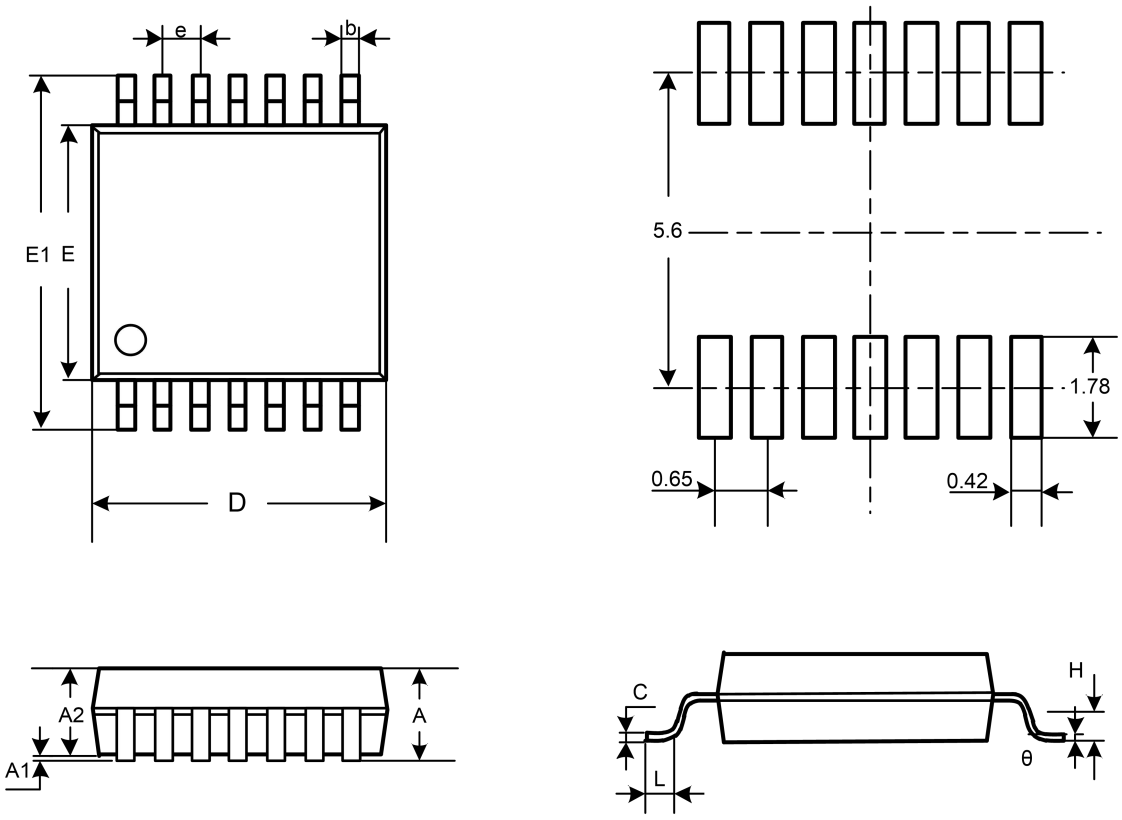
BOTTOM VIEW



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Min
A	0.450	0.550	0.018	0.022
A1	0.000	0.050	0.000	0.002
c	0.100	0.200	0.004	0.008
b	0.150	0.250	0.006	0.010
D	1.900	2.100	0.075	0.083
E	1.900	2.100	0.075	0.083
D2	1.000	1.200	0.039	0.057
E2	1.000	1.200	0.039	0.057
e	0.400BSC		0.016BSC	
h	0.150	0.250	0.006	0.010
L	0.150	0.250	0.006	0.010

12 Package Outline Dimension(Continued)

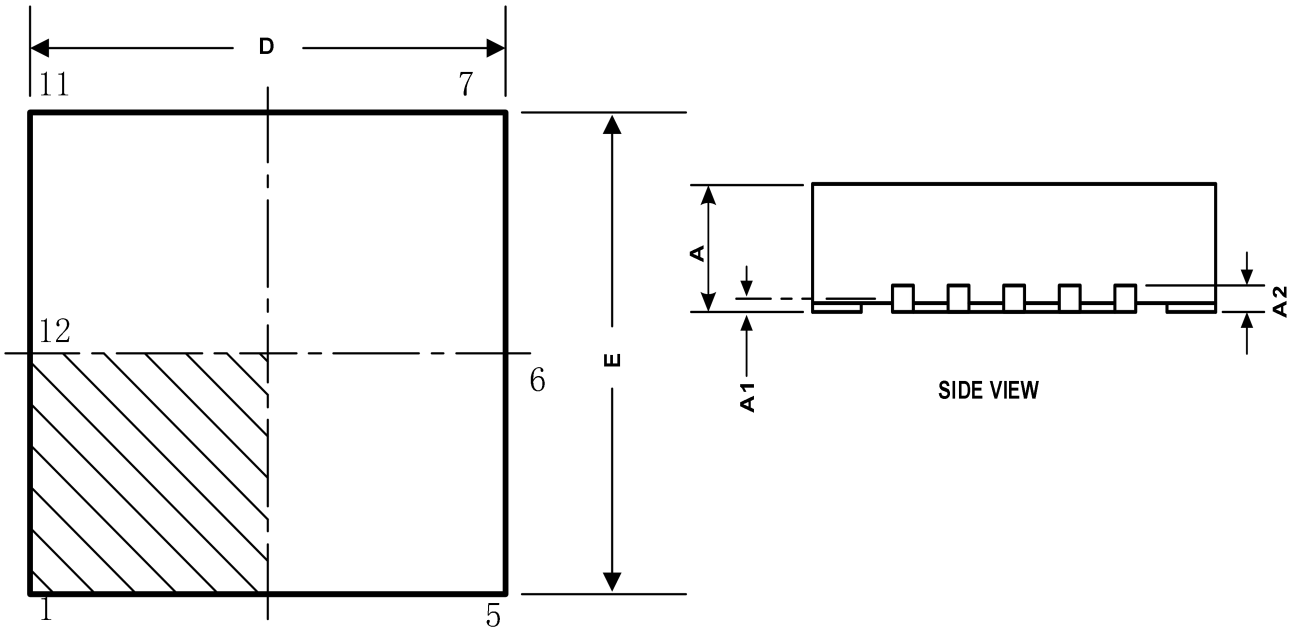
TSSOP-14



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Min
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650BSC		0.026BSC	
L	0.500	0.700	0.020	0.028
H	0.250TYP		0.010TYP	
θ	1°	7°	1°	7°

12 Package Outline Dimension(Continued)

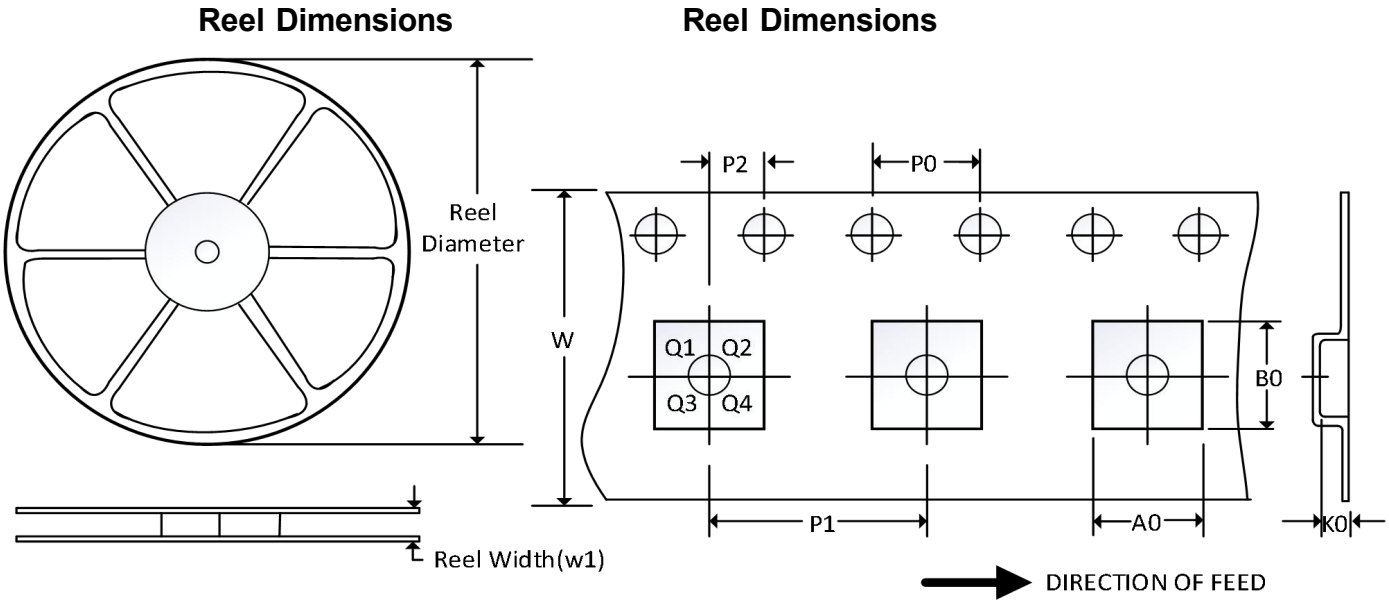
QFN2.0×1.7-12L



TOP VIEW

Symbol	Dimensions in millimeters		Dimensions in inches	
	Min	Max	Min	Min
A	0.450	0.550	0.018	0.022
A1	0.000	0.050	0.000	0.002
A2	0.152REF		0.006REF	
D	1.900	2.100	0.075	0.086
E	1.600	1.800	0.063	0.071
D2	1.500	1.700	0.059	0.067
b	0.150	0.250	0.006	0.010
b1	0.150REF		0.006REF	
K	0.250REF		0.010REF	
e	0.400BSC		0.016BSC	
L	0.400	0.600	0.016	0.024

13 Tape and Reel Information



Note: The picture is only for reference. Please make the object as the standard.

Key Parameter List of Tape and Reel

Package Type	Reel Diameter	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 QuAdrant
QFN3.5×3.5-14L	13''	12.4	4.0	4.0	1.10	4.0	8.0	2.0	12.0	Q1
QFN2.0×2.0-12L	7''	9.0	2.13	2.13	0.88	4.0	4.0	2.0	8.0	Q1
TSSOP-14	13''	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1
QFN2.0×1.7-12L	7''	9.0	1.90	2.30	0.75	4.0	4.0	2.0	8.0	Q1

Note:
(1)All dimensions are nominal.
(2)Plastic or metal protrusions of 0.15mm maximum per side are not included.